

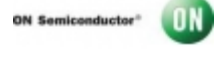



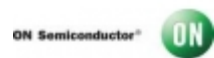
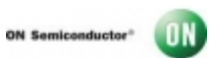
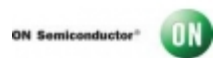

	<h2 style="color: red;">H11A617BSD</h2> <p>Hersteller-Teilenummer: H11A617BSD</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: OPTOISO 5.3KV TRANSISTOR 4SMD</p> <hr/> <p>Datenblätter:  H11A617BSD.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 80000 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p>Not Actual Photo YIC International Co., Limited.</p>	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	H11A617BSD
Hersteller	Fairchild/ON Semiconductor
Beschreibung	OPTOISO 5.3KV TRANSISTOR 4SMD
Kategorie	Isolatoren > Optoisolatoren - Transistor, Photovoltaik-
Teilstatus	80000 pcs Stock
Serie	-
Eingabetyp	DC
Betriebstemperatur	-55°C ~ 100°C
Befestigungsart	Surface Mount
Ausgabebetyp	Transistor
Anzahl der Kanäle	1
Verpackung / Gehäuse	4-SMD, Gull Wing
Supplier Device-Gehäuse	4-SMD
Strom - Ausgang / Kanal	50mA
Spannung - Isolation	5300Vrms
Aufstieg / Fallzeit (Typ)	2.4µs, 2.4µs
Spannung - Ausgabe (max)	70V
Spannung - Vorwärts (Vf) (Typ)	1.35V
Strom - DC Vorwärts (If) (Max)	50mA
Gleichstrom-Übertragungsverhältnis (min)	63% @ 10mA
Stromübertragungsverhältnis (max)	125% @ 10mA
Ein- / Ausschaltzeit (Typ)	-
VCE Sättigung (max)	400mV
Verpackung	Tape & Reel (TR)

H11A617BSD ist neu im Original, Suche H11A617BSD Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie H11A617BSD Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage H11A617BSD: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>H11A617B3SD AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A617BW Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4DIP</p>	 <p>H11A617C Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4DIP</p>	 <p>H11A617BS Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>
 <p>H11A617B3S AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A617BSD AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A617BS AMI Semiconductor / ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>	 <p>H11A617B3SD Fairchild/ON Semiconductor OPTOISO 5.3KV TRANSISTOR 4SMD</p>

heiße Teile

Mehr

H11A4SVM	H11A4SVM	H11A4TVM	D H11A4TVM	H11A5100
H11A5100SR2M	H11A5SR2M	D H11A5SR2M	H11A5SR2VM	H11A5SR2VM
H11A5SVM	H11A5SVM	H11A5TVM	H11A5TVM	H11A617A3SD
D H11A617A3SD	H11A617B	H11A617B	H11A617B300	H11A617B300
H11A617B3SD	H11A617B3SD	H11A617BS	H11A617BS	H11A617BSD
H11A617CSD	H11A617CSD	D H11A617D3SD	H11A617D3SD	H11A814C
H11A817A	D H11A817A	H11A817A.3SD	H11A817A3SD	H11A817A3SD
H11A817ASD	H11A817ASD	H11A817B	H11A817B	H11A817B.3SD
H11A817B300	H11A817B300	H11A817B3SD	D H11A817B3SD	H11A817BSD
H11A817BSD	H11A817BW	H11A817BW	H11A817C	H11A817C

Contact us:Info@Y-IC.com

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